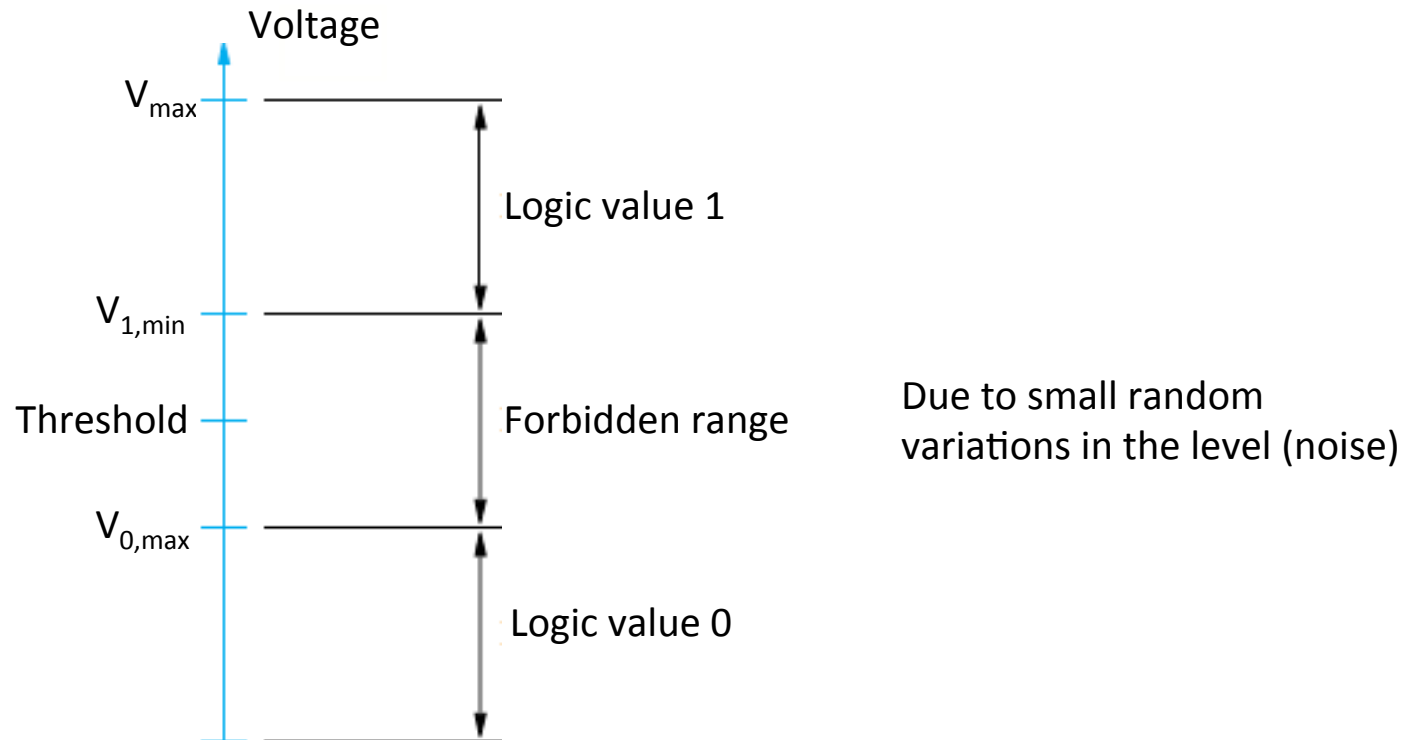


Logic variables have values of 1 and 0, or “high” and “low”

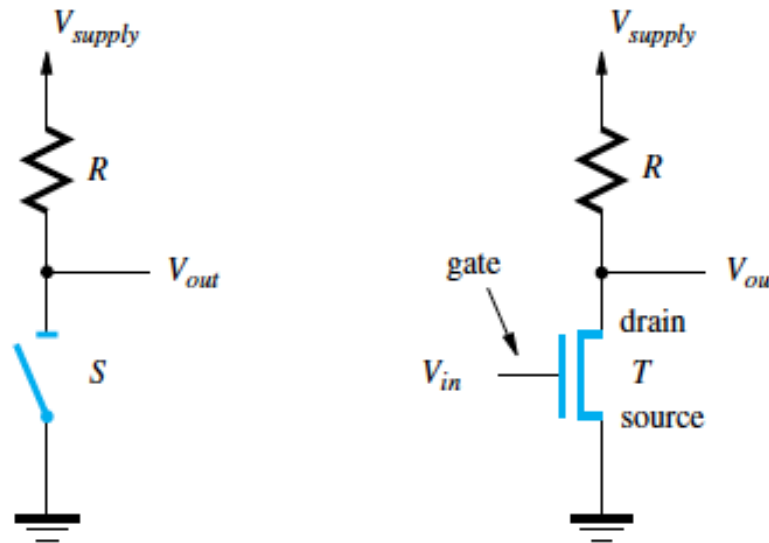
Voltages or currents can represent logic variables

Values above a given threshold represent one state (“on” or “off”)

Values below the threshold represent the opposite state



Digital systems use transistors as switches



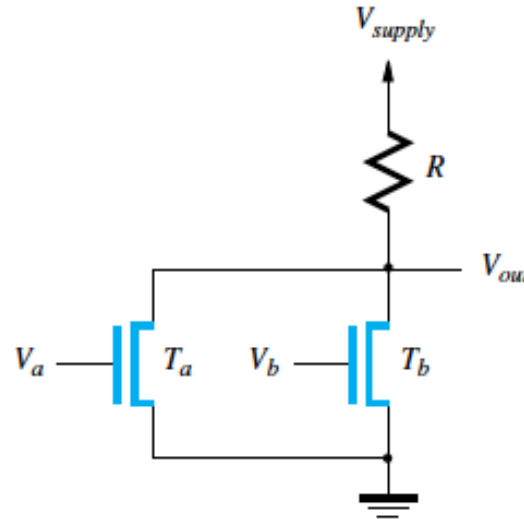
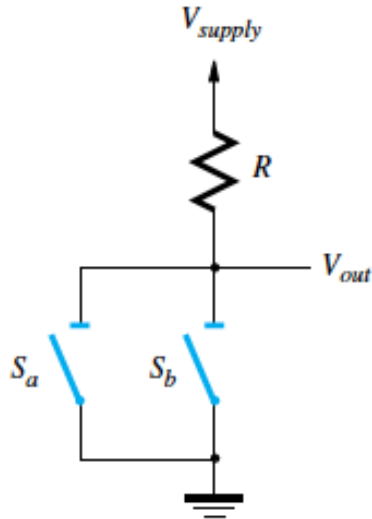
Acts as an inverter

$V_{out} = V_{supply}$ (1) when the switch is open

$V_{out} = 0$ when the switch is closed

Transistor act as an open switch when $V_{in} = 0$

Transistor act as a closed switch when $V_{in} = 1$



Acts as NOR Gate

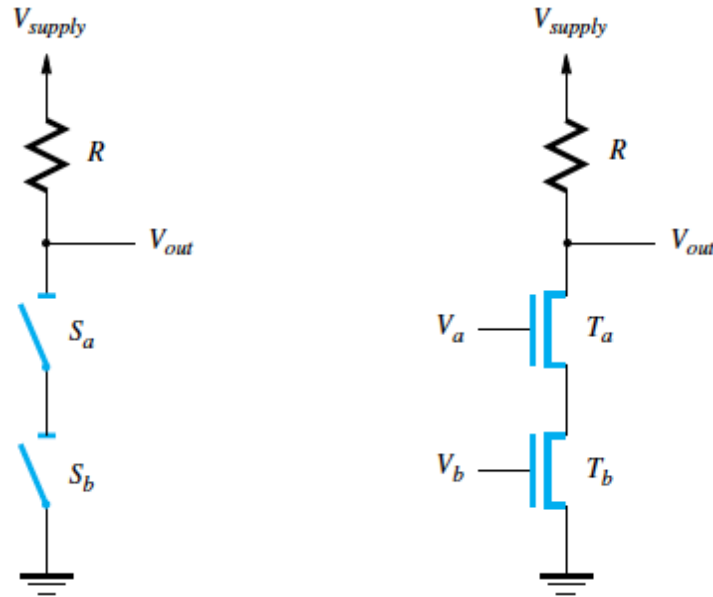
V_a	V_b	V_{out}
0	0	1
0	1	0
1	0	0
1	1	0

$V_{out} = 0$ when either switch is closed

$V_{out} = 1$ when both switches are open

Transistor act as an open switch when $V_{in} = 0$

Transistor act as a closed switch when $V_{in} = 1$



Acts as NAND Gate

V_a	V_b	V_{out}
0	0	1
0	1	1
1	0	1
1	1	0

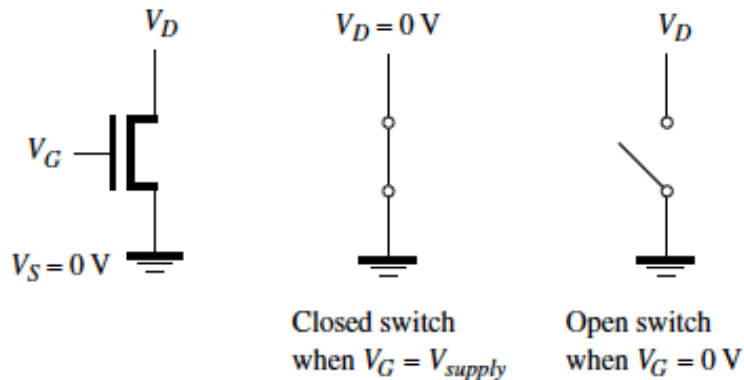
$V_{out} = 1$ when either switch is open

$V_{out} = 0$ when both switches are closed

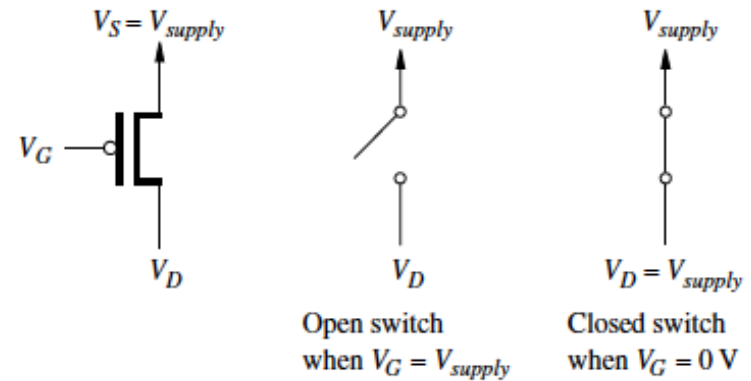
AND and OR can be implemented from NAND and NOR gates

Just use NOT gate to invert output of NAND or NOR gates

So more transistors are required for AND and OR gates



NMOS Transistor



PMOS Transistor

Two types of metal-oxide semiconductor (MOS) are available
NMOS-type behave as closed switch when the gate voltage is high
PMOS-type behave as closed switch when the gate voltage is low
Inversion bubble on input denotes PMOS

Source for NMOS transistor is connected to ground (0)

Source for PMOS transistor is connected to V_{supply} (1)

When the switches are closed, current flows

- Power is consumed by current flowing through the resistor

- More heat results when more power is dissipated

CMOS circuits combine NMOS and PMOS transistors

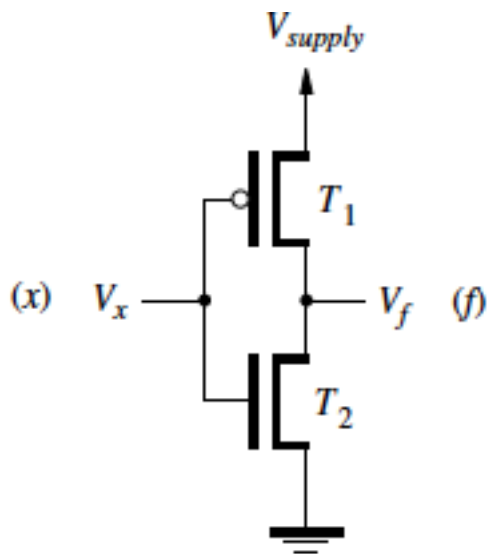
- CMOS means complementary metal-oxide semiconductor

- CMOS circuits consume less power

MOS transistors occupy a very small area on IC chips

- Billions can fit on a single integrated circuit (IC) chip

- Smaller transistors can switch at extremely high rates (GHz range)



Circuit

$$(V_f = \text{NOT } V_x)$$

x	V_x	T_1	T_2	V_f	f
0	low	on	off	high	1
1	high	off	on	low	0

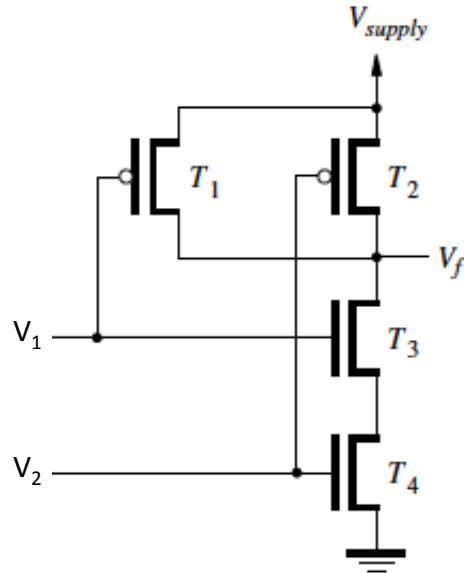
Truth table and transistor states

$V_x=0$ closes T_1 and opens T_2 , pulling V_f up to V_{supply}

$V_x=1$ closes T_2 and opens T_1 , pulling V_f down to 0

So V_f is the complement of V_x

T_1 and T_2 operate in a complementary fashion



Circuit

$$(V_f = V_1 \text{ NAND } V_2)$$

V_1	V_2	T_1	T_2	T_3	T_4	f
0	0	on	on	off	off	1
0	1	on	off	off	on	1
1	0	off	on	on	off	1
1	1	off	off	on	on	0

Truth table and transistor states

If T_1 or T_2 is closed V_f is pulled up to V_{supply}

$V_1 = 0$ closes T_1 ; $V_2 = 0$ closes T_2

If T_3 and T_4 are closed V_f is pulled down to 0

$V_1 = 1$ closes T_1 ; $V_2 = 1$ closes T_2

Dissipates power only when switching